Supplementary Imformation

Precursor-Dependent Shape Variation of Wurtzite CdSe Crystals

in a Microwave-Assisted Polyol Process

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Fig. S1 EDX spectra of CdSe crystals grown in ethylene glycol for 10 min at X values of 0 (a) and 0.8 (b). The Si peak has originated from the silicon wafer substrate.



Fig. S2 Photoluminescence spectra of as-prepared CdSe crystals produced in ethylene glycol at various X values indicated inside. All of the samples were suspended in ethanol at room temperature and excited at 355 nm.



Fig. S3 TEM images of CdSe crystals grown at X values 0.8 in glycerol for 10 min.



Fig. S4 HRXRD patterns of the reference wurtzite CdSe (black), the reference trigonal bulk selenium (blue), and crystals grown at an X value of 1.0 in glycerol (red) and ethylene glycol (green).